BSS84L, BVSS84L

Power MOSFET Single P-Channel SOT-23 -50 V, 10 Ω

- SOT-23 Surface Mount Package Saves Board Space
- AEC Q101 Qualified and PPAP Capable BVSS84L
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSS}	50	Vdc
Gate-to-Source Voltage - Continuous	V_{GS}	± 20	Vdc
Drain Current Continuous @ T _A = 25°C Pulsed Drain Current (t _p ≤ 10 μs)	I _D I _{DM}	130 520	mA
Total Power Dissipation @ $T_A = 25^{\circ}C$	PD	225	mW
Operating and Storage Temperature Range	T _J , T _{stg}	– 55 to 150	°C
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Maximum Lead Temperature for Soldering Purposes, for 10 seconds	ΤL	260	°C

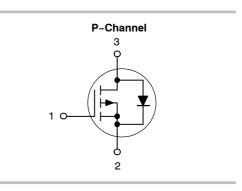
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



ON Semiconductor®

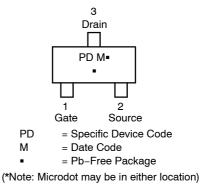
http://onsemi.com

V _{(BR)DSS}	R _{DS(ON)} MAX
–50 V	10 Ω @ 10 V





MARKING DIAGRAM & PIN ASSIGNMENT



ORDERING INFORMATION

Device	Package	Shipping [†]
BSS84LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
BVSS84LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BSS84L, BVSS84L

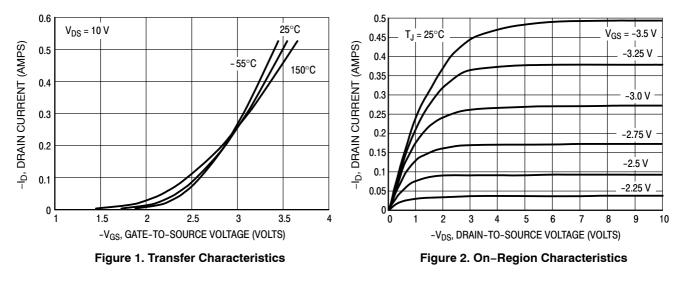
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Chara	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						-
Drain-to-Source Breakdown Voltage (V _{GS} = 0 Vdc, I _D = -250 μ Adc)	V _{(BR)DSS}	-50	-	_	Vdc	
$ \begin{array}{l} \mbox{Zero Gate Voltage Drain Current} \\ (V_{DS} = -25 \mbox{ Vdc}, V_{GS} = 0 \mbox{ Vdc}) \\ (V_{DS} = -50 \mbox{ Vdc}, V_{GS} = 0 \mbox{ Vdc}) \\ (V_{DS} = -50 \mbox{ Vdc}, V_{GS} = 0 \mbox{ Vdc}, T_J \end{array} $	I _{DSS}		- - -	-0.1 -15 -60	μAdc	
Gate-Body Leakage Current (V _{GS} = :	± 20 Vdc, V _{DS} = 0 Vdc)	I _{GSS}	-	-	±10	nAdc
ON CHARACTERISTICS (Note 1)						
Gate-Source Threaded Voltage (V _{DS}	= V_{GS} , I_D = -250 μ A)	V _{GS(th)}	-0.9	-	-2.0	Vdc
Static Drain-to-Source On-Resistan	R _{DS(on)}	-	4.7	10	Ω	
Transfer Admittance (V _{DS} = -25 Vdc,	y _{fs}	50	-	-	mS	
DYNAMIC CHARACTERISTICS						
Input Capacitance	$V_{DS} = 5.0 \text{ Vdc}$	C _{iss}	-	36	-	pF
Output Capacitance	$V_{DS} = 5.0 \text{ Vdc}$	C _{oss}	-	17	-	
Transfer Capacitance	V _{DG} = 5.0 Vdc	C _{rss}	I	6.5	-	
SWITCHING CHARACTERISTICS (M	lote 2)					
Turn-On Delay Time		t _{d(on)}	-	3.6	-	ns
Rise Time	V _{DD} = -15 Vdc, I _D = -2.5 Adc,	t _r	-	9.7	-	
Turn-Off Delay Time	$R_L = 50 \Omega$	t _{d(off)}	-	12	-	
Fall Time		t _f	_	1.7	-	1
Gate Charge	V _{DD} = -40 Vdc, I _D = -0.5 A, V _{GS} = -10 V	QT	-	2.2	-	nC

Continuous Current	۱ _S	-	-	-0.130	А	
Pulsed Current			-	-	-0.520	
Forward Voltage (Note 2)	$V_{GS} = 0 \text{ V}, \text{ I}_{S} = -130 \text{ mA}$	V _{SD}	-	-	-2.2	V

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
Switching characteristics are independent of operating junction temperature.

TYPICAL ELECTRICAL CHARACTERISTICS



BSS84L, BVSS84L

TYPICAL ELECTRICAL CHARACTERISTICS

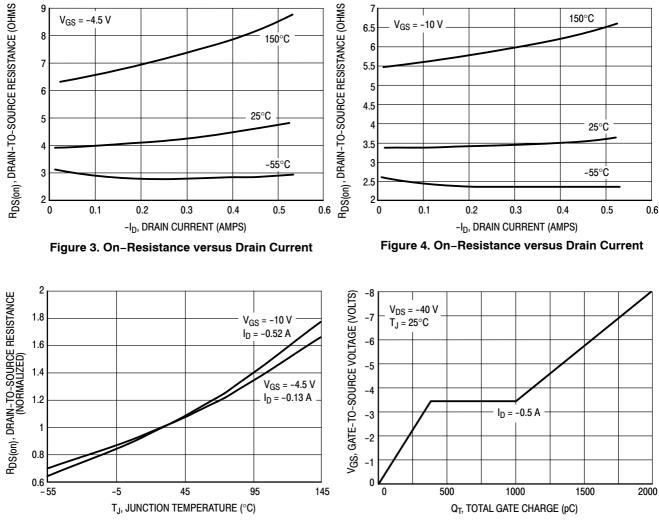


Figure 5. On-Resistance Variation with Temperature

Figure 6. Gate Charge

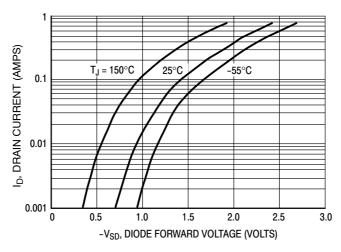


Figure 7. Body Diode Forward Voltage

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP**

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION- INCLI
- З.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

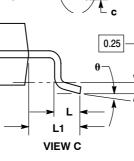
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.89	1.00	1.11	0.035	0.040	0.044	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.37	0.44	0.50	0.015	0.018	0.020	
c	0.09	0.13	0.18	0.003	0.005	0.007	
D	2.80	2.90	3.04	0.110	0.114	0.120	
E	1.20	1.30	1.40	0.047	0.051	0.055	
е	1.78	1.90	2.04	0.070	0.075	0.081	
L	0.10	0.20	0.30	0.004	0.008	0.012	
L1	0.35	0.54	0.69	0.014	0.021	0.029	
HE	2.10	2.40	2.64	0.083	0.094	0.104	
θ	0°		10°	0°		10°	



b

HE

È

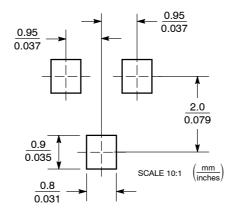


SEE VIEW C



3. DRAIN

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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